Analog Switch

HITACHI

ADE-205-308C (Z) 4th. Edition April 2001

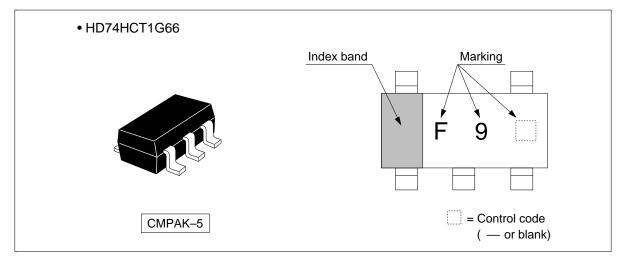
Description

The HD74HCT1G66 is high speed CMOS analog switch using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed. The device has low ON resistance for good transfer characteristics and can take wide range of input voltage.

Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- Control input is TTL compatible input level. Supply voltage range : 4.5 to 5.5 V Operating temperature range : -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$

Outline and Article Indication



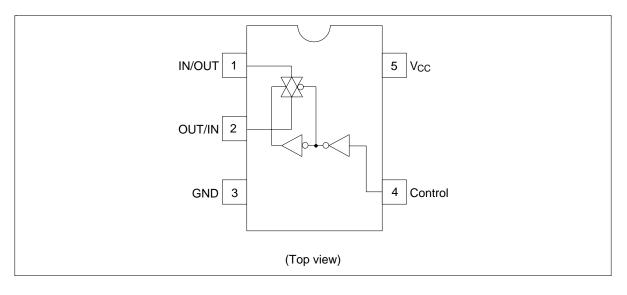


Function Table

Control	Switch	
L	OFF	
Н	ON	
H : Hiah level		

L : Low level $GND \le V_{IN} \le V_{CC}$ $GND \le V_{OUT} \le V_{CC}$

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	–0.5 to 7.0	V	
Input voltage range *1	V	–0.5 to V _{cc} + 0.5	V	
Output voltage range *1, 2	Vo	–0.5 to V _{cc} + 0.5	V	Output : H or L
Input clamp current	I _{IK}	±20	mA	$V_1 < 0 \text{ or } V_1 > V_{cc}$
Output clamp current	Ι _{οκ}	±20	mA	$V_o < 0 \text{ or } V_o > V_{cc}$
Continuous output current	I _o	±25	mA	$V_{o} = 0$ to V_{cc}
Continuous current through V_{cc} or GND	$I_{\rm CC} \text{ or } I_{\rm GND}$	±25	mA	
Maximum power dissipation at Ta = 25° C (in still air) ^{'3}	ιΡ	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was caluculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Test Conditions
Supply voltage range	V _{cc}	4.5	5.5	V	
Input voltage range	V	0	5.5	V	
Output voltage range	V _{I/O}	0	V _{cc}	V	
Input rise / fall time (Control input 0.3 V to 2.7 V)	t _r , t _f	0	500	ns	V_{cc} = 4.5 to 5.5 V
Operating temperature	Та	-40	85	°C	

Note: Unused or floating control inputs must be held high or low.

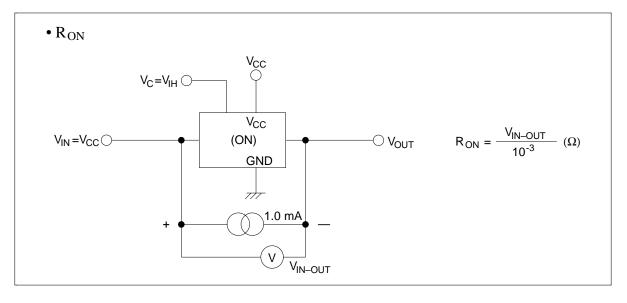
Electrical Characteristics

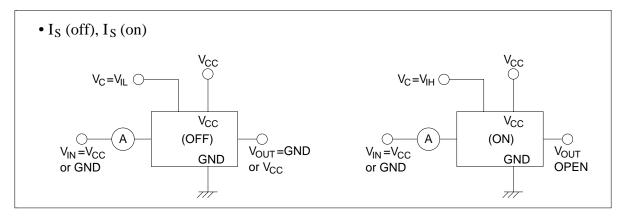
Item	Symbol	\mathbf{V}_{cc}	T _a = 2	5°C		$T_a = -40$ to $85^{\circ}C$		Unit	Test Conditions
		(V)	Min	Тур	Мах	Min	Max	-	
Input voltage	V _{IH}	4.5 to 5.5	2.0	_	_	2.0	_	V	Control input only
	V _{IL}	4.5 to 5.5			0.8		0.8	-	
On resistance	R _{on}	4.5 to 5.5		100	200		250	Ω	$V_{c} = V_{iH}$ $V_{iN} = 0 \text{ to } V_{cc}$ $I_{iN/OUT} = 1 \text{ mA}$
Leak current	I _s (off)	5.5	_	_	±0.1	_	±1.0	μΑ	
	I _s (on)	5.5	_		±0.1	_	±1.0	μA	$V_{c} = V_{H}$ $V_{IN} = V_{CC}$ or GND
Input current	I _{IN}	5.5	_	_	±0.1	_	±1.0	μA	$V_{IN} = V_{CC}$ or GND
Operating current	I _{cc}	5.5	_		1.0		10.0	μA	$V_{IN} = V_{CC}$ or GND
Quiescent supply current	I _{CCT}	5.5			2.0		2.9	mA	$V_{c} = 2.4 V,$ V_{iN} (switch) = V_{cc} or GND

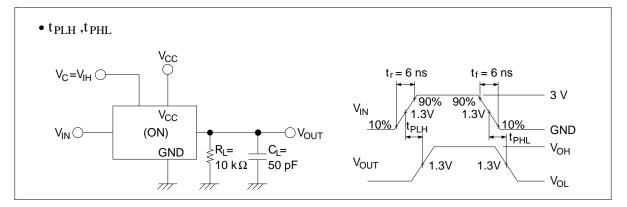
Switching Characteristics

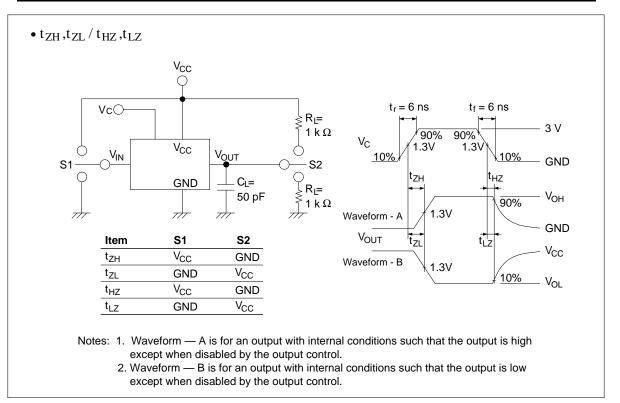
Item	Symbol	\mathbf{V}_{cc}	T _a = 25°C		T _a = −40 to 85°C		Unit	Test Conditions	
		(V)	Min	Тур	Max	Min	Max	-	
Propagation delay time	$t_{_{PLH}},t_{_{PHL}}$	4.5	_	4	10	_	13	ns	$R_{L} = 10 \ k\Omega$
Output enable time	t_{zH}, t_{zL}	4.5	_	10	23	_	29	ns	$R_{L} = 1 \ k\Omega$
Output disable time	$t_{HZ}^{}, t_{LZ}^{}$	4.5	—	14	23	—	29	ns	$R_{L} = 1 \ k\Omega$
Maximum control frequency		4.5	_	30				MHz	
Control input capacitance	CIN			2.5	5		5	pF	
Switch I/O capacitance	C _{IN/OUT}			2.5				pF	
Feed through capacitance	$C_{\text{IN-OUT}}$		_	0.5	_	_	_	pF	
Power dissipation capacitance	C _{PD}		_	5	_			pF	

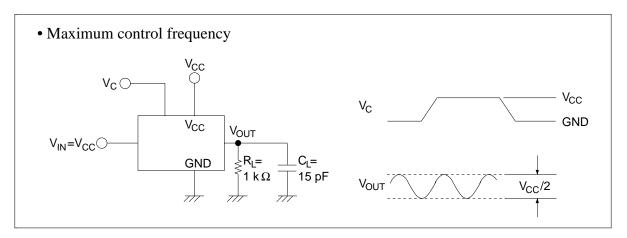
Test Circuit

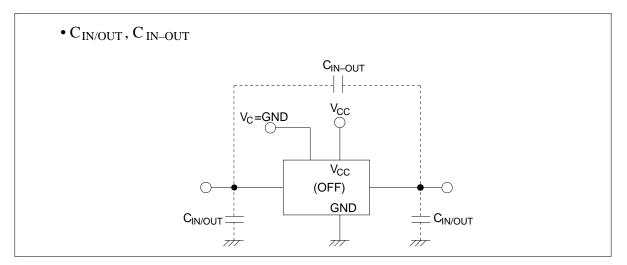




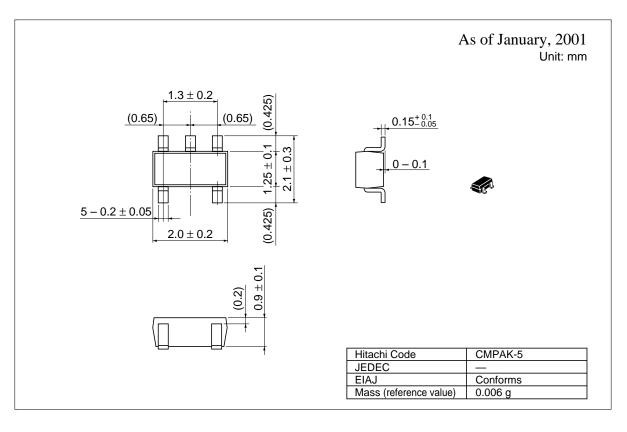








Package Dimensions



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